

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
1	BRS	L1	6	"6744091"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 15:03			
2	IS&R	L2	20	((("5,502,336") or ("5,479,054") or ("5,338,700") or ("4,974,040") or ("5,150,278") or ("5,196,910") or ("5,605,857") or ("5,324,681") or ("5,292,677") or ("5,281,549")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 15:14			
3	BRS	L4	1049	etch\$3 same ((first and second and third) adj (insulat\$3 or dielectric)) same (cob or memory or dram or capacitor or storage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 15:18			
4	BRS	L5	865	etch\$3 same ((first same second same third) adj (insulat\$3 or dielectric)) same (cob or memory or dram or capacitor or storage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 15:53			
5	BRS	L6	0	4 and @pd<="02240311"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 15:20			
6	BRS	L7	806	4 and @pd<="20040311"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 15:56			
7	BRS	L8	98	etch\$3 same ((first same second same third) adj (insulat\$3 or dielectric)) same (cob or memory or dram or capacitor or storage) same conductor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 17:56			

8	BRS	L9	67	8 and @pd<="20040311"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 16:04			
---	-----	----	----	-----------------------	-------------------------------------------------------------------	------------------	--	--	--

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
9	BRS	L10	15	8 and @pd<="19960126"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 17:57			
10	BRS	L12	0	etch\$3 same ((first same second same third same fourth) adj (insulat\$3 or dielectric)) same (cob or memory or dram or capacitor or storage) same conductor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 17:57			
11	BRS	L14	49	etch\$3 same ((first same second same third same fourth) adj (insulat\$3 or dielectric)) same (cob or memory or dram or capacitor or storage) same conductor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 17:57			
12	BRS	L15	6	14 and @pd<="19960126"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 18:33			
13	BRS	L17	10	ANEZAKI-TOHRU.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 18:34			
14	BRS	L16	259	EMA-TAIJI.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 18:34			